NSN 5962-01-361-6518

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View Online at https://aerobasegroup.com/nsn/5962-01-361-6518

Body Length:

1.490 inches

Body Width:

Between 0.500 inches and 0.610 inches

Body Height:

0.217 inches

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

B-2

Features Provided:

Hermetically sealed and burn in and monolithic and positive outputs

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

N-type metal oxide-semiconductor logic

Input Circuit Pattern:

26 input

Criticality Code Justification:

Feat

Case Outline Source And Designator:

D-10 mil-m-38510

Current Rating Per Characteristic:

120.00 milliamperes reverse current, dc absolute

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-1.0 volts power source and 7.0 volts power source

Capitance Rating Per Characteristic:

6.00 input picofarads and 10.00 output picofarads

Time Rating Per Chacteristic:

250.00 nanoseconds access

Memory Device Type:

Eeprom

Special Features:

Nuclear hardness critical item

Nuclear Hardness Critical Feature:

Hardened

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Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

28 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0